

# Electric field dependence of pairing temperature and tunneling

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Using the Bethe-Salpeter equation including high electric fields, the dependence of the critical temperature of onsetting superconductivity on the applied field is calculated analytically. The critical temperature of pairing is shown to increase with the applied field strength. This is a new field effect and could contribute to the explanation of recent experiments on field induced superconductivity. From the field dependence of the Bethe-Salpeter equation, the two-particle bound state solution is obtained as a resonance with a tunneling probability analogous to the WKB solution of a single particle confined in a potential and coupled to the electrical field.

The influence of static electric fields on superconducting properties has been investigated for nearly 40 years [1] but has gained renewed experimental interest [2,3,4], see also overview in [5]. Recently, field-induced superconductivity in a spin-ladder cuprate, where the critical temperature raised to 14 K by applying high gate voltages has been reported [6]. A wide experimental activity on high- $T_c$  superconductors has been devoted to this change of the critical temperature and transport properties due to an external electric field [7,8,2,9,3,10]. Consequently a considerable theoretical effort has been made to describe such field effects [11,12,13].

Usually two standard mechanisms have been proposed in high  $T_c$ -cuprates [14], see [5] and citations therein. The first one describes the changes of hole concentration due to Coulomb force of the external field and the second mechanism describes the field-induced oxygen rearrangement [15]. These mechanisms will change the density of state and consequently the order parameter. As a result one expects frustration of charge density waves [16] connected with specific threshold electric fields [17] and a nonlinear conductivity [18]. However, the nonlinear field dependence of the current showed that there must be a field effect besides the change of carrier density [4].

For very clean and thin two-dimensional structures with high transversal electric fields one can expect that the pairing mechanism by itself and the two-particle correlations will be influenced by the field since the direct current as the dominant effect of the field is suppressed by the geometry. This was first investigated in a quasi-one-dimensional conductor [19]. For general dimensions one best work within the field dependent Bethe-Salpeter equation. We will find that the pairing mechanism is affected itself analogously to the formation of sidebands in the density of states due to high fields for one particle properties [20]. Here we will show that the two-particle Bethe-Salpeter equation becomes field dependent and consequently also the resulting critical temperature. In an earlier paper [21] it was demonstrated that the in-

clusion of high electric fields leads to novel modifications of the two-particle properties : (i) The bound states, reflected by the value  $\pi$  of the phase shift at low energies are turned into resonances, (ii) The Pauli-blocking effect (which turns the phase shift to negative values, indicating effective repulsive behavior of the scattering) is suppressed by the applied field. This is understood as the opening of a scattering channel due to the field. (iii) The onset of pairing and superfluidity (which is reflected as a sharp resonance at energies twice the chemical potential) is observed at higher temperatures with increasing field.

Here in this letter we will concentrate on the latter effect and will derive an analytical expression of the increase of the critical temperature with the applied field. In order to see the expected field effects we consider the two-particle phase factor for free charged particles in a constant electric field  $\mathbf{E}$  [ $t = (t_1 + t_2)$ ,  $\tau = t_1 - t_2$ ]

$$\begin{aligned} & \exp \left( -\frac{i}{\hbar} \int_{t_1}^{t_2} dt \left( \frac{(\mathbf{p} + e_1 \mathbf{E}t)^2}{2m_1} + \frac{(-\mathbf{p} + e_2 \mathbf{E}t)^2}{2m_2} \right) \right) \\ &= \exp \left[ \frac{i}{\hbar} \tau \left( \frac{p^2}{2\mu_{12}} - \frac{E^2}{2} \left( \frac{e_1^2}{m_1} + \frac{e_2^2}{m_2} \right) t^2 \right) \right. \\ & \quad \left. - \frac{i}{\hbar} \left( \frac{e_1}{m_1} - \frac{e_2}{m_2} \right) \mathbf{p} \mathbf{E} t \tau - i \frac{E^2}{8\hbar} \left( \frac{e_1^2}{m_1} + \frac{e_2^2}{m_2} \right) \frac{\tau^3}{3} \right], \end{aligned}$$

where three different actions of the applied field occur. The first term proportional to  $t^2$  can be absorbed into a redefinition of the chemical potential, i.e. the background. The second term, proportional to  $t$  and linear in the field, is vanishing for equal mass to charge ratios as considered here. The last term, proportional to  $E^2$ , is linked to the third power of the difference time  $\tau$  and is therefore due to off-shellness. It is not vanishing for equal charge-to-mass ratios and will turn out as the essential term responsible for the here described modification of pairing and tunneling. The typical energy scale which appears here is

$$\lambda_E = \left( \frac{E^2 \hbar^2}{8} \left( \frac{e_a^2}{m_a} + \frac{e_b^2}{m_b} \right) \right)^{\frac{1}{3}}. \quad (1)$$

In the following we proceed to investigate the two-particle properties more closely by solving the Bethe-Salpeter equation. We intend to show that the applied electric field is leading to a new field effect to the critical temperature. Therefore we do not explain how superconductivity is occurring or which inhomogeneity of the gap might be necessary [22,23] but concentrate on the change of the critical temperature provided we do have superconductivity.

In [21] we have shown that the gauge-invariant formulation of the one- and two-particle Green's function leads to a field,  $\mathbf{E}$ , and time,  $t$ , dependent Bethe-Salpeter equation for the  $\mathcal{T}$ -matrix with the difference momenta of incoming channel  $\mathbf{p}$  and of outgoing channel  $\mathbf{p}'$ , which can be solved with separable potentials  $V(p, p') = \lambda g(p)g(p')$ . For our case of equal particles it reads as

$$\langle \mathbf{p} | \mathcal{T}^R(\mathbf{K}, \omega, t) | \mathbf{p}' \rangle = \frac{\lambda g(\mathbf{p}')g(\mathbf{p})}{1 - \lambda J(\mathbf{K}, \mathbf{E}, \omega, t)}, \quad (2)$$

with

$$J = \int \frac{d\bar{\mathbf{p}}}{(2\pi\hbar)^3} g(\bar{\mathbf{p}})^2 \Phi(\varepsilon_a + \varepsilon_b - \omega) \left( 1 - f_{\frac{\mathbf{K}}{2} - \bar{\mathbf{p}}}^a - f_{\frac{\mathbf{K}}{2} + \bar{\mathbf{p}}}^b \right) \quad (3)$$

where the arguments of the quasiparticle energy  $\varepsilon_{a/b}$  are the same as the one of the distribution functions  $f^{a/b}$ . The center of mass momentum is  $\mathbf{K}$  and the function  $\Phi$  is given in terms of Airy-functions, [24]

$$\Phi(\omega) = \frac{\pi}{\lambda_E} \left( \text{Gi}\left(\frac{\omega}{\lambda_E}\right) + i \text{Ai}\left(\frac{\omega}{\lambda_E}\right) \right) \rightarrow \frac{1}{\omega + i0} \text{ for } E=0. \quad (4)$$

The usual Bethe-Salpeter equation is recovered in the field-free case. The occupation factors  $f^{a/b}$  are the one-particle distribution functions resembling the Pauli-blocking of the intermediate propagator. At equilibrium we have correspondingly Fermi distributions.

The denominator of the  $\mathcal{T}$ -matrix determines the resonances or bound states which may occur in the system. Due to the equal charge-to-mass ratios, in which case the center of mass time dependence drops out of the equation, the only remaining center of mass time dependence is in the center of mass momentum  $\mathbf{K}$  but which is suppressed due to geometric quasi-2D restriction.

In order to demonstrate the field effects, we use the model of a contact potential. This is most easily obtained from the separable potential by the limit of zero range, which means  $g(p) \rightarrow \infty$ , in such a way that the scattering length is reproduced. This is accomplished by adapting  $\lambda$  accordingly. Therefore the scattering amplitude is normalized properly to render finite results. The definition of the scattering length  $a$  is given by the small wavelength expansion of the scattering phase shift

$$p \cot \delta = p \frac{\text{Re} \mathcal{T}}{\text{Im} \mathcal{T}} = p \frac{1 - \lambda \text{Re} J_0(\varepsilon(p))}{\lambda \text{Im} J_0(\varepsilon(p))} \approx -\frac{\hbar}{a} \quad (5)$$

which we use to replace the strength  $\lambda$  of the potential by the scattering length and perform the limit to the contact potential by  $g(p) \rightarrow \infty$ . The  $\mathcal{T}$ -matrix reads then

$$\begin{aligned} \mathcal{T}_{pp'}(\omega) &= \frac{g(p)g(p')}{\text{Re} J_0(\varepsilon(p)) - \frac{\hbar}{ap} \text{Im} J_0(\varepsilon(p)) - J(\omega)} \\ &\rightarrow \frac{1}{\text{Re} J_0(\varepsilon(p)) - \frac{\hbar}{ap} \text{Im} J_0(\varepsilon(p)) - J(\omega)}, \end{aligned} \quad (6)$$

with  $J(\omega)$  given by (3) but without form factor  $g(p) \rightarrow 1$  and  $J_0 = J[f \rightarrow 0]$ . Now we search for a pairing resonance which appears as a jump in the phase shift by  $\pi$  at twice the chemical potential,  $2\mu$ , in the field free case. For the field dependent case there will be a shift of this two particle threshold  $2\mu + \zeta$  according to the Stark effect. The conditions for such a pairing resonance is that  $\tan \delta$  has a pole with vanishing strength. From (5) and (6) follows

$$\begin{aligned} \text{Re} J_0(\varepsilon(p)) - \text{Re} J(2\mu + \zeta) &= \frac{\hbar}{ap} \text{Im} J_0(\varepsilon(p)) \\ \text{Im} J(2\mu + \zeta) &= 0. \end{aligned} \quad (7)$$

In the field free case we have from (6)  $\text{Im} J_0 = N(p)\pi$  with the density of states  $N(p)$ . The real part diverges by itself, but the difference  $\text{Re}(J - J_0)$  remains finite. This can be either realized by a finite range of potential and a corresponding finite form factor  $g(p)$ , or, alternatively, by an energy cutoff  $\omega_c \ll \mu$ . We will adopt here the later possibility since it compares to the standard BCS treatment. Since  $\text{Im} J_0(2\mu) = 0$ , we obtain from (7) with  $V_0 = 4\pi a \hbar^2 / m$  the usual BCS equation for the critical temperature

$$N(p_f) \int_0^{\omega_c} \frac{d\xi}{2\xi} \tanh \frac{\xi}{2T_0} = -\frac{1}{V_0}. \quad (8)$$

For the field dependent case we have to solve the coupled equation system (7) for the energy shift  $\zeta$  and the critical field  $T_0$ . Further we allow a nontrivial realistic density of states  $N$ , for instance due to layered structures. According to (3) and (4) the kernel of  $\text{Im} J$  is the Airy function. Expanding the second equation of (7) in terms of the field parameter  $\lambda_E$  we obtain to the lowest order,  $\zeta = -\lambda_E^3 / 24T_c^2 + o(\lambda_E)^6$ , analogously to the quadratic Stark effect. We will now solve the equation for the critical temperature and will find that it leads to results  $\sim \lambda_E$ . Therefore we can neglect the influence of  $\zeta$  on the first equation of (7), it being of higher order, and obtain with (4)

$$-\frac{1}{N(p_f)V_0} = \int_{-\omega_c}^{\omega_c} d\xi \frac{\pi}{\lambda_E} \text{Gi}\left(\frac{2\xi}{\lambda_E}\right) \tanh \frac{\xi}{2T_c} =$$

$$\int_0^{\omega_c} d\xi \left[ \frac{1}{2\xi} - \frac{\pi^{1/2}}{(2\xi\lambda_E^3)^{1/4}} \cos\left(\frac{2}{3}\left(\frac{2\xi}{\lambda_E}\right)^{3/2} + \frac{\pi}{4}\right) \right] \tanh \frac{\xi}{2T_c}, \quad (9)$$

where we have used the asymptotic expansion for the  $Gi$  function for small  $\lambda_E$ . We remark that they are different above and below the Fermi energy in contrast to the field-free case. Please not also that this field dependent modification can be considered as an effective field dependent density of state. This shows that the Anderson theorem [25] is fulfilled which states, that for a homogeneous perturbation and order parameter the critical temperature can only be effected by the density of states.

Since  $\omega_c/T$  is very large, the first part of (9) can be integrated in the standard manner [26],

$$\int_0^{\omega_c} \frac{d\xi}{2\xi} \tanh \frac{\xi}{2T_c} = \frac{1}{2} \ln \frac{\omega_c}{T_c} [1 - 2f(\omega_c)] + \int_0^{\omega_c/T_c} dx \ln x \frac{d}{dx} \left( \frac{1}{e^x + 1} \right) \approx \frac{1}{2} \ln \frac{a\omega_c}{T_c} \quad (10)$$

and  $a = 2e^\gamma/\pi \approx 1.134$ . The second part of (9) can be expanded up to  $o(\lambda_E/T_c)^5$

$$\frac{\lambda_E}{8T} \sqrt{\pi} \int_0^{2\omega_c/\lambda_E} dp p^{3/4} \cos\left(\frac{2}{3}p^{3/2} + \frac{\pi}{4}\right) = -\frac{\lambda_E}{T} b \quad (11)$$

with  $b = \frac{3^{2/3}\sqrt{\pi}}{2^{1/6}} \left( \frac{1}{32}\Gamma\left(\frac{7}{6}\right) + \frac{3}{112}\Gamma\left(\frac{13}{6}\right) \right) \approx 0.190$ . Using the result for the field-free case  $T_0[N] = a\omega_c \exp(-2/|V_0|N)$  dependent on the doping concentration, we obtain finally the field-dependent critical temperature

$$T_c \ln \frac{T_c}{T_0[N]} = b\lambda_E + o(\lambda_E/T_c)^5 \quad (12)$$

from which one gets  $T_c - T_0[N] \approx \lambda_E b$  for small fields. Please remark that the doping concentration condensed in the density of states  $N$  is field dependent itself such that Eq.(12) is an effect on top of the doping dependence which might be an explanation for the nonlinear dependence found in [2,4]. Within the regime  $\lambda_E \ll T_c \ll \omega_c \ll \epsilon_f$  we find an increase of  $T_c$  with the applied field. For other expansions of (9) one finds a decrease, like when  $\lambda_E \sim \omega_c$  which has been reported in [19]. The result here, (12), represents a new field effect. All field effects considered so far in the literature due to the increase of doping or the change of bands are condensed in the above  $T_0[N(p_f)]$  parameter.

In figure 1 we compare the solution of (12) with the experimental values of [6]. This experiment has been performed on a field effect transistor device of  $[\text{CaCu}_2\text{O}_3]_4$

films on a MgO substrate covered by an insulating  $\text{Al}_2\text{O}_3$  sheet. The capacitance of this insulating sheet is 120 nF/cm<sup>2</sup>. With a ratio of dielectric constants between the insulator and the cuprate of  $\epsilon_{\text{ins}}/\epsilon_{\text{cup}}$ , the effective electric field strength in the active sheet depends on the applied voltage  $U$  as  $0.135\epsilon_{\text{ins}}/\epsilon_{\text{cup}} \times U/\text{nm}$ . We assume that above a critical voltage sufficient charges are doped into the cuprate surface layer such that correlations and pairing occurs. This threshold voltage was at about 118V assuming  $T_0 = 1\text{K}$ . Above this threshold the field effects act as derived above. The best fit of the dielectric constants between insulator and cuprates are found here  $\epsilon_{\text{ins}}/\epsilon_{\text{cup}} \approx 192$ . Nearly the same figure appears if we set  $\epsilon_{\text{ins}}/\epsilon_{\text{cup}} \approx 10$  and  $T_0 = 2 \times 10^{-8}$  K which is probably more realistic since  $\epsilon_{\text{ins}}/\epsilon_{\text{cup}} = 0.7$  [27].

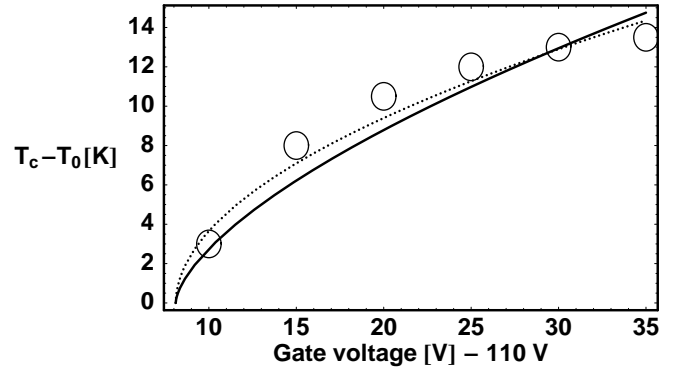


FIG. 1. The critical temperature in dependence on the applied voltage according to (12). The circles gives the experimental values of [6]. The solid line gives the theoretical value of (12) for  $\epsilon_{\text{ins}}/\epsilon_{\text{cup}} \approx 10$  and  $T_0 = 2 \times 10^{-8}$  K while the dashed line is for  $\epsilon_{\text{ins}}/\epsilon_{\text{cup}} \approx 192$  and  $T_0 = 1$  K.

The field dependence changes directly the two-particle correlations, which leads to an increase of the critical temperature  $\sim U^{2/3}$  of the applied voltage. Of course, at higher voltages the breakthrough occurs limiting this effect. A more realistic calculation would be to solve (9) directly as well as realistic density of states  $N(p_f)$ . This will lead to a nonlinear decrease of the curve in figure 1 for higher applied fields and is devoted to a forthcoming work.

Here it has to be remarked that the discussed experimental values do not allow to conclude uniquely on this new field effect. As long as the doping concentration  $N$  is not simultaneously measured one cannot decide how much field effect is on top of the conventional  $T_0[N]$  result according to (12).

In order to gain some trust into the theoretical treatment above we want to investigate now possible bound states of the field dependent Bethe Salpeter equation. A bound state, parameterized by a negative (attractive) scattering length, should turn into a resonance with finite lifetime when the field is applied.

Neglecting the medium effects condensed in the oc-

cupation numbers, we obtain with quadratic dispersion from (3) after some analytical work for 3D

$$\begin{aligned}\text{Im } J(z) &= \frac{m\sqrt{m\lambda_E}}{\hbar^3 2^{5/3}} (\text{Ai}'^2(z) - z\text{Ai}^2(z)) \\ \text{Re } J(z) &= \frac{m\sqrt{m\lambda_E}}{\hbar^3 2^{5/3}} (\text{Ai}'(z)\text{Bi}'(z) - z\text{Ai}(z)\text{Bi}(z)),\end{aligned}\quad (13)$$

with  $z = -\frac{p^2}{m2^{2/3}\lambda_E}$  for  $J(\frac{p^2}{m})$  and  $z = \frac{|\omega|}{2^{2/3}\lambda_E}$  for  $J(\omega)$ , respectively, and standard Airy functions. Together with (6), this represents the result for the field dependent Bethe-Salpeter equation in high electric fields. Analogous formulae can be given for 2D. The negative poles of this equation provides us with the influence of the field on the bound states. The latter one is realized by choosing the attractive contact potential in a way that the negative squared scattering length (5) reproduces the bound state energy  $\omega = -E_0 = -\hbar^2/ma^2$ . It is interesting to see that for vanishing fields,  $\lambda_E \rightarrow 0$ , we get from (13) that  $\text{Im}J(\frac{p^2}{m}) \rightarrow mp/4\pi\hbar^3$  and  $\text{Re}J(\omega) \rightarrow -m^{3/2}\sqrt{|\omega|}/4\pi\hbar^3$  while  $\text{Re}J(\frac{p^2}{m}) = \text{Im}J(\omega) \rightarrow 0$ , which leads from (6) to the known field-free on-shell  $\mathcal{T}$ -matrix  $\mathcal{T}_{E=0}(\frac{p^2}{m}) = -\frac{4\pi\hbar^3}{m} / (\frac{\hbar}{a} + ip)$ .

For small fields we investigate now the bound states and expand (6) up to  $o(\lambda_E^3)$  field effects. The bound or resonance states are given by the pole of the  $\mathcal{T}$ -matrix and we must search for the complex zeros of  $\omega$  via

$$\mathcal{T}^{-1}(\omega) \frac{4\pi\hbar^3}{m^{3/2}} = -\frac{\hbar}{a\sqrt{m}} + \sqrt{|\omega|} - i\frac{\lambda_E^{3/2}}{4|\omega|} e^{-\frac{2}{3}(\frac{|\omega|}{\lambda_E})^{3/2}} = 0.\quad (14)$$

The pole-value of the T-matrix is now a resonance  $|\omega| = -E_0 + \Delta + i\frac{\hbar}{\tau}$ , and reads in the lowest expansion  $o(\lambda_E)^{7/2}$

$$\begin{aligned}\Delta &= \frac{\lambda_E^3}{16E_0^2} \left( 3 + 4 \left( \frac{-E_0}{\lambda_E} \right)^{3/2} \right) \exp \left( -\frac{4}{3} \left( \frac{-E_0}{\lambda_E} \right)^{3/2} \right) \\ \frac{\hbar}{\tau} &= \frac{\lambda_E^{3/2}}{2\sqrt{-E_0}} \exp \left( -\frac{2}{3} \left( \frac{-E_0}{\lambda_E} \right)^{3/2} \right).\end{aligned}\quad (15)$$

If one particle is very heavy,  $m_b \rightarrow \infty$ , and counting the bound state energy  $-E_0 = U_0 - \epsilon$  from the continuum threshold  $U_0$ , we obtain from (15)

$$\frac{\hbar}{\tau} \sim \exp \left( -\frac{4\sqrt{2m}}{3e\hbar E} (U_0 - \epsilon)^{3/2} \right)\quad (16)$$

which is exactly the known WKB result for one particle tunneling through a potential wall modified by an external field  $U_0 - Ex$ . Consequently, (15) generalizes the known WKB result towards the two-particle problem in electric fields. The bound state energy and the damping or inverse lifetime (15) increases with increasing fields.

To summarize, we have analyzed the two-particle Bethe-Salpeter equation with respect to the critical temperature of pairing and bound states when an external electric field is applied. The critical temperature rises with the applied field strength. This establishes an isotropic field effect directly on the pairing mechanism beyond the ones considered so far. The bound states turn into resonances where the life time and energy shift of the two-particle bound state is given explicitly. As another application we may also think of the pair creation in high fields as it appears in the neighborhood of big charged nuclei as electron positron production or as meson production when strings are breaking.

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Note added in proof:

Recently the Lucent report by Bell Labs ([http://www.lucnet.com/news\\_events/researchreview.html](http://www.lucnet.com/news_events/researchreview.html)) found scientific misconduct in a series of experimental results. The data which are used in this paper here are not among the objected ones in this report and are a result of a broader cooperation.

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